# HEF4007UB

# Dual complementary pair and inverter Rev. 4 — 31 August 2017

**Product data sheet** 

#### 1 **General description**

The HEF4007UB is a dual complementary pair and an inverter with access to each device. It has three n-channel and three p-channel enhancement mode MOS transistors.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to V<sub>DD</sub>, V<sub>SS</sub>, or another input.

#### Features and benefits

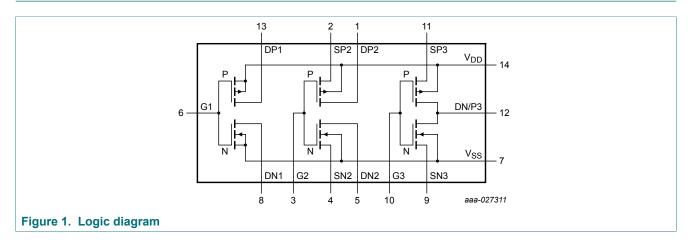
- · Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- · Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B
- Inputs and outputs are protected against electrostatic effects

#### 3 **Ordering information**

**Table 1. Ordering information** 

Type number Package					
	Temperature range	Name	Description	Version	
HEF4007UBT	-40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1	

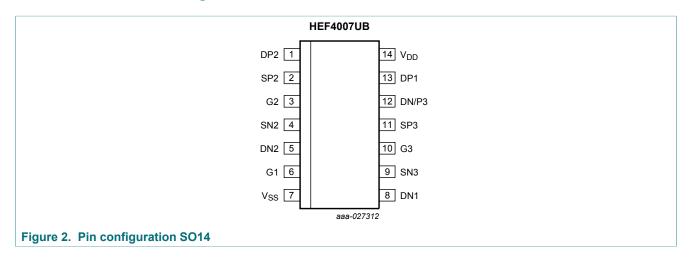
#### **Functional diagram** 4





# **5** Pinning information

## 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
DP1, DP2	13, 1	drain connections from the 1st and 2nd p-channel transistors
SP2, SP3	2, 11	source connections to 2nd and 3rd p-channel transistors
G1, G2, G3	6, 3, 10	gate connections to n-channel and p-channel of the three transistor pairs
SN2, SN3	4, 9	source connections to the 2nd and 3rd n-channel transistors
DN1, DN2	8, 5	drain connection from the 1st and 2nd n-channel transistors
DN/P3	12	common connection to the 3rd p-channel and n-channel transistor drains
V <sub>SS</sub>	7	ground (0 V)
$V_{DD}$	14	supply voltage

# 6 Limiting values

#### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to  $V_{\rm SS}$  = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current		-	±10	mA
VI	input voltage		-0.5	V <sub>DD</sub> + 0.5	V
I <sub>OK</sub>	output clamping current		-	±10	mA
I <sub>I/O</sub>	input/output current		-	±10	mA
I <sub>DD</sub>	supply current		-	50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to + 85 °C			
		SO14 [1]	-	500	mW
Р	power dissipation	per output	-	100	mW

<sup>[1]</sup> For SO14 packages: above  $T_{amb}$  = 70 °C,  $P_{tot}$  derates linearly with 8 mW/K.

# 7 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD}$	supply voltage		3	-	15	V
VI	input voltage		0	-	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V <sub>DD</sub> = 5 V	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

## 8 Static characteristics

Table 5. Static characteristics

 $V_{SS}$  = 0 V;  $V_I$  =  $V_{SS}$  or  $V_{DD}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>DD</sub>	T <sub>amb</sub> = -40 °C		T <sub>amb</sub> = +25 °C		T <sub>amb</sub> = +85 °C		Unit
				Min	Max	Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level input voltage	$V_O = 0.5 \text{ V or } 4.5 \text{ V};$ $ I_O  < 1 \mu A$	5 V	4	-	4	-	4	-	V
		V <sub>O</sub> = 1.0 V or 9.0 V;  I <sub>O</sub>   < 1 μΑ	10 V	8	-	8	-	8	-	V
		$V_O = 1.5 \text{ V or } 13.5 \text{ V};$ $ I_O  < 1 \mu A$	15 V	12.5	-	12.5	-	12.5	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_O = 0.5 \text{ V or } 4.5 \text{ V};$ $ I_O  < 1 \mu A$	5 V	-	1	-	1	-	1	V
		V <sub>O</sub> = 1.0 V or 9.0 V;  I <sub>O</sub>   < 1 μA	10 V	-	2	-	2	-	2	V
		$V_O = 1.5 \text{ V or } 13.5 \text{ V};$ $ I_O  < 1 \mu A$	15 V	-	2.5	-	2.5	-	2.5	V
$V_{OH}$	HIGH-level output voltage	$V_I = V_{SS}$ or $V_{DD}$ ; $ I_O  < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	٧
$V_{OL}$	LOW-level output voltage	. 00 22,101 1	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I <sub>OH</sub>	HIGH-	V <sub>O</sub> = 2.5 V; V <sub>I</sub> = 0 V	5 V	-	-1.7	-	-1.4	-	-1.1	mA
	level output (source)current	V <sub>O</sub> = 4.6 V; V <sub>I</sub> = 0 V	5 V	-	-0.52	-	-0.44	-	-0.36	mA
	,	V <sub>O</sub> = 9.5 V; V <sub>I</sub> = 0 V	10 V	-	-1.3	-	-1.1	-	-0.9	mA
		V <sub>O</sub> = 13.5 V; V <sub>I</sub> = 0 V	15 V	-	-3.6	-	-3.0	-	-2.4	mA
I <sub>OL</sub>	LOW-level	V <sub>O</sub> = 0.4 V; V <sub>I</sub> = 5 V	5 V	0.52	-	0.44	-	0.36	-	mA
	output (sink)current	V <sub>O</sub> = 0.5 V; V <sub>I</sub> = 10 V	10 V	1.3	-	1.1	-	0.9	-	mA
	, , , , , , , , , , , , , , , , , , , ,	V <sub>O</sub> = 1.5 V; V <sub>I</sub> = 15 V	15 V	3.6	-	3.0	-	2.4	-	mA
I <sub>I</sub>	input leakage current	V <sub>I</sub> = 0 V to 15 V	15 V	-	±0.3	-	±0.3	-	±1.0	μA
I <sub>DD</sub>	supply current	all valid input combinations;	5 V	-	1.0	-	1.0	-	7.5	μΑ
		$V_I = V_{SS}$ or $V_{DD}$ ; $I_O = 0$ A	10 V	-	2.0	-	2.0	-	15.0	μA
			15 V	-	4.0	-	4.0	-	30.0	μΑ

# 9 Dynamic characteristics

#### **Table 6. Dynamic characteristics**

 $T_{amb}$  = 25 °C; for waveforms see Figure 3; for test circuit see Figure 4; unless otherwise specified.

Symbol	Parameter	Conditions	Extrapolation formula [1]	$V_{DD}$	Min	Тур	Max	Unit
t <sub>PHL</sub>	HIGH to LOW	Gn to Dn or DP	13 + 0.55 × C <sub>L</sub>	5 V	-	40	80	ns
	propagation delay		9 + 0.23 × C <sub>L</sub>	10 V	-	20	40	ns
			7 + 0.16 × C <sub>L</sub>	15 V	-	15	30	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	Gn to Dn or DP	13 + 0.55 × C <sub>L</sub>	5 V	-	40	75	ns
			9 + 0.23 × C <sub>L</sub>	10 V	-	20	40	ns
			7 + 0.16 × C <sub>L</sub>	15 V	-	15	30	ns
t <sub>t</sub>	output transition time [2]		10 + 1.0 × C <sub>L</sub>	5 V	-	60	120	ns
			9 + 0.42 × C <sub>L</sub>	10 V	-	30	60	ns
			6 + 0.28 × C <sub>L</sub>	15 V	-	20	40	ns

<sup>[1]</sup> The typical value of the propagation delay and output transition time can be calculated with the extrapolation formula (C<sub>L</sub> in pF).

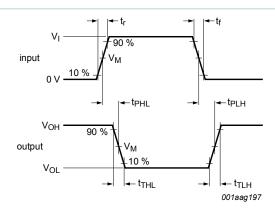
Table 7. Dynamic power dissipation

 $V_{SS} = 0$  V;  $t_r = t_f \le 20$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	V <sub>DD</sub>	Typical formula	Where
$P_D$	dynamic power	5 V	. (0 2)	f <sub>i</sub> = input frequency in MHz;
dissipation		10 V	F	f <sub>o</sub> = output frequency in MHz; C <sub>L</sub> = output load capacitance in pF;
		15 V	D = 50000 x f + 5/f x C \ x \ / \ 2 (.\\\)	$\Sigma(f_0 \times C_L)$ = sum of the outputs; $V_{DD}$ = supply voltage in V.

<sup>[2]</sup> t<sub>t</sub> is the same as t<sub>THL</sub> and t<sub>TLH</sub>.

#### 9.1 Waveforms and test circuit



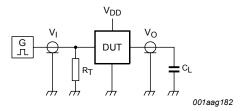
Measurement points are given in Table 8.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Figure 3. Propagation delay, output transition time

Table 8. Measurement points

Supply voltage	Input	Output
$V_{DD}$	$V_{M}$	V <sub>M</sub>
5 V to 15 V	0.5V <sub>DD</sub>	0.5V <sub>DD</sub>



Test data is given in Table 9.

Definitions for test circuit:

C<sub>L</sub> = load capacitance including jig and probe capacitance.

 $R_T$  = termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

Figure 4. Test circuit for measuring switching times

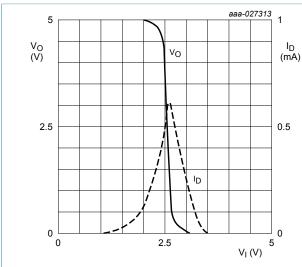
Table 9. Test data

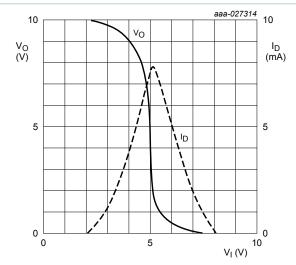
Supply voltage	Input	Load	
$V_{DD}$	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub>
5 V to 15 V	V <sub>SS</sub> or V <sub>DD</sub>	≤ 20 ns	50 pF

HEF4007UB

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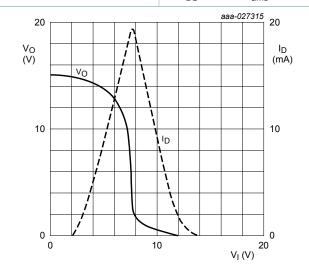
#### 9.2 Characteristics





a.  $V_{DD}$  = 5 V;  $T_{amb}$  = 25 °C

b.  $V_{DD}$  = 10 V;  $T_{amb}$  = 25 °C



c.  $V_{DD}$  = 15 V;  $T_{amb}$  = 25 °C

Figure 5. Typical drain current I<sub>D</sub> and output voltage V<sub>O</sub> as functions of input voltage

## 10 Application information

Some examples of applications for the HEF4007UB are:

- · High input impedance amplifiers
- · Linear amplifiers
- (Crystal) oscillators
- · High-current sink and source drivers
- High impedance buffers

#### Note:

Rules for maintaining electrical isolation between transistors and monolithic substrate:

- The V<sub>DD</sub> supply pin (Pin 14) must be maintained at the most positive (or equally positive) potential with respect to any other pin of the HEF4007UB.
- The V<sub>SS</sub> ground pin (Pin 7) must be maintained at the most positive (or equally positive) potential with respect to any other pin of the HEF4007UB.

Violation of these rules will result in improper transistor operation and/or possible permanent damage to the HEF4007UB.

<u>Figure 6</u> and <u>Figure 7</u> show voltage gain and supply current. <u>Figure 8</u> shows the test set-up and an example of an analog amplifier using one HEF4007UB.

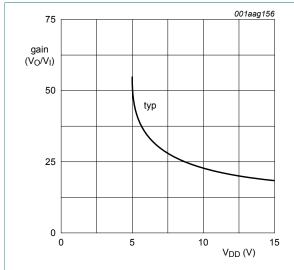


Figure 6. Typical voltage gain as a function of supply voltage

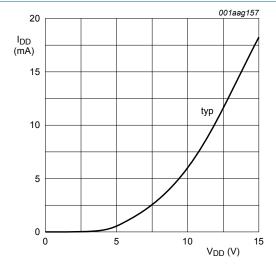


Figure 7. Typical supply current as a function of supply voltage



Figure 8. Test set-up

HEF4007UE

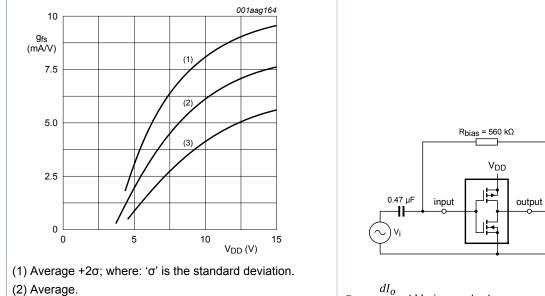
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100 μF

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#### **Dual complementary pair and inverter**

Figure 9 shows typical forward transconductance and Figure 10 shows the test set-up.



(3) Average  $-2\sigma$ ; where: ' $\sigma$ ' is the standard deviation.

Figure 9. Typical forward transconductance as a function of supply voltage at  $T_{amb}$  = 25 °C

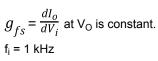
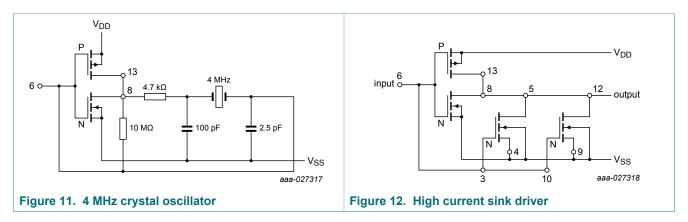


Figure 10. Test set-up

Figure 11, Figure 12, Figure 13 and Figure 14 show some applications in which the HEF4007UB is used.



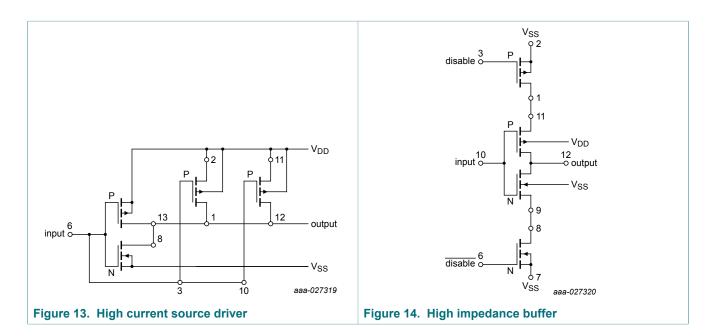


Table 10. Function table [1]

For Figure 14. High impedance buffer

Input	Disable	Output
Н	L	L
L	L	Н
X	Н	Z

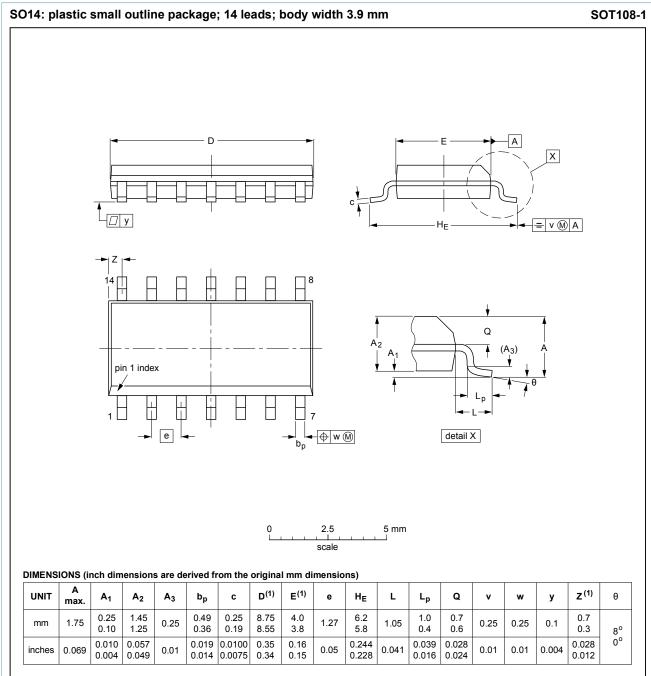
<sup>[1]</sup> H = HIGH state (the more positive voltage);

L = LOW state (the less positive voltage);

X = state is immaterial

Z = HIGH-impedance OFF-state

# 11 Package outline



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				<del>99-12-27</del> 03-02-19

Figure 15. Package outline SOT108-1 (SO14)

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## 12 Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
DUT	Device Under Test
MOS	Metal Oxide Semiconductor

# 13 Revision history

#### Table 12. Revision history

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Document ID	Release date	Data sheet status	Change notice	Supersedes	
HEF4007UB v.4	20170831	Product data sheet	-	HEF4007UB v.3	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number HEF4007UBP and HEF4007UBD removed.</li> </ul>				
HEF4007UB v.3	19951201	Product specification	-	-	

## 14 Legal information

#### 14.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### **Dual complementary pair and inverter**

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